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PATENT ASSIGNMENT COVER SHEET

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SUBMISSION TYPE: NEW ASSIGNMENT

NATURE OF CONVEYANCE: ASSIGNMENT

EPAS ID: PAT4165974

CONVEYING PARTY DATA

Name	Execution Date
BLANDINE DURIEZ	09/22/2015
MARTIN CHRISTOPHER HOLLAND	09/22/2015
YEE-CHIA YEO	09/24/2015

RECEIVING PARTY DATA

Name:	TAIWAN SEMICONDUCTOR MANUFACTURING COMPANY, LTD.
Street Address:	NO. 8, LI-HSIN RD. 6
Internal Address:	SCIENCE-BASED INDUSTRIAL PARK
City:	HSIN-CHU
State/Country:	TAIWAN
Postal Code:	300-77

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	14868641

CORRESPONDENCE DATA

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ATTORNEY DOCKET NUMBER:	24061.3189US01
NAME OF SUBMITTER:	DELL WHITTON
SIGNATURE:	/Dell Whitton/
DATE SIGNED:	12/01/2016

Total Attachments: 2

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PATENT 504119304 REEL: 040486 FRAME: 0348

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Docket No.: P20150808US00/24061.3189US01

Customer No.: 000042717

ASSIGNMENT

WHEREAS, we,

- (1) Blandine Duriez of Bruxelles, Belgium, Germany
 (2) Martin Christopher Holland of Bertem, Belgium, Germany
- (3) Yee-Chia Yeo of Hsinchu City, Taiwan, Republic of China

have invented certain improvements in

HIGH DENSITY NANOWIRE ARRAY

for which we have executed an application for Letters Patent of the United States of America,

X	of even date filed herewith; and
	filed on 09-29-2015 and assigned application number 14/868,641, and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Company, Ltd., ("TSMC"), No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park Hsin-Chu, Taiwan 300-77, Republic of China is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths

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and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name:

Blandine Duriez

Residence Address:

clos des Peupliers 11 1200 Bruxelles, Belgium, Germany-

Dated: $\frac{22/09/2015}{}$

Inventor Signature

Inventor Name:

Martin Christopher Holland

Residence Address:

Tervuursesteenweg 547, Leefdaal, 3061, Bertem, Belgium, Germany...

Dated: 22 /09/2015

M C+1-ttm

Inventor Name:

Yee-Chia Yeo

Residence Address:

50 Daxue Road, 7 Floor, Apartment 2 Hsinchu City, Taiwan Republic of China

Dated: Sy. 24, 2015.

Inventor Signature